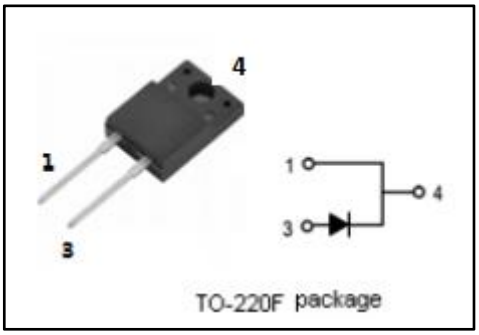
Ultrafast Rectifier MUR10120

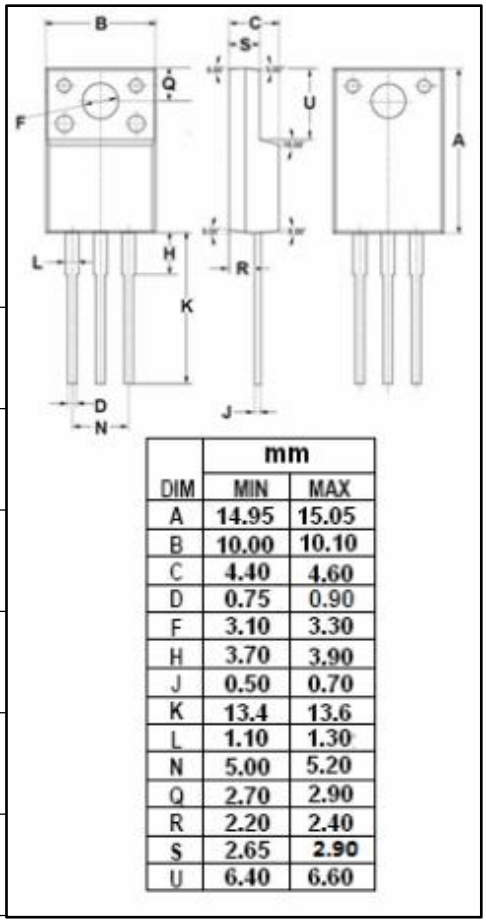
FEATURES

- 1200V blocking voltage
- 20mJ avalanche energy
- 12V(typical) peak transient overshoot voltage
- 135ns (typical) forward recovery time
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

- This power rectifier is specifically designed for use as damper diode in horizontal deflection circuits for high and very high resolution monitors



DIM	mm MIN	MAX
A	14.95	15.05
B	10.00	10.10
C	4.40	4.60
D	0.75	0.90
F	3.10	3.30
H	3.70	3.90
J	0.50	0.70
K	13.4	13.6
L	1.10	1.30
N	5.00	5.20
Q	2.70	2.90
R	2.20	2.40
S	2.65	2.90
U	6.40	6.60

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V_{RRM} V_{RWM} V_R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	1200	V
$I_{F(AV)}$	Average Rectified Forward Current	10	A
I_{FSM}	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	100	A
T_J	Junction Temperature	-65~150	℃
T_{stg}	Storage Temperature Range	-65~150	℃

Fast Recovery Rectifier MUR10120

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j\text{-}c}$	Thermal Resistance,Junction to Case	2.0	℃/W

ELECTRICAL CHARACTERISTICS(T_a=25℃) (Pulse Test: Pulse Width=300 μ s,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V_{F*}	Maximum Instantaneous Forward Voltage	I_F=6.5A ;Tj=25℃ I_F= 6.5A ;Tj=125℃	2.2 2.0	V
I_{R*}	Maximum Instantaneous Reverse Current	V_R= $V_{RWM;}$Tj=125℃ V_R= V_{RWM}	1000 100	μ A
t_{rr}	Maximum Reverse Recovery Time	IF =1A;di/dt = 50A/μs	175	ns

*:Pulse test ,Pulse width=300us,duty cycle≤2%